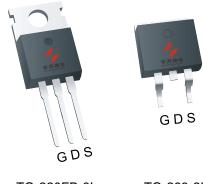


#### N-Channel Enhancement Mode MOSFET

#### **Feature**

- 100V/135A $R_{DS(ON)} = 5 \text{ m}\Omega(\text{typ.}) \text{ @VGS} = 10V$
- 100% Avalanche Tested
- 100% DVDS
- Reliable and Rugged
- Halogen Free and Green Devices Available (RoHS Compliant)

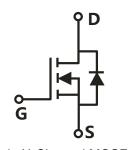
## **Pin Description**



TO-220FB-3L TO-263-2L

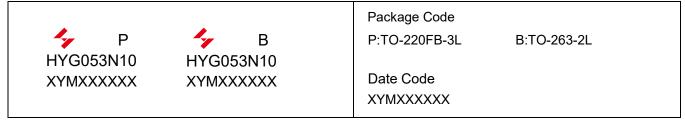
## **Applications**

- Switching application
- Li-battery protection
- DC-DC
- Motor control



Single N-Channel MOSFET

## Ordering and Marking Information



Note: HUAYI halogen free products contain molding compounds and 100% matte tin plate Termi-Nation finish; which are fully compliant with RoHS. HUAYI halogen free products meet or exceed the halogen free require-ments of IPC/JEDEC J-STD-020 for MSL classification at halogen free peak reflow temperature. HUAYI defines "Green" to mean halogen free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

HUAYI reserves the right to make changes, corrections, enhancements, modifications, and improvements to this pr-oduct and/or to this document at any time without notice.



# **Absolute Maximum Ratings**

| Symbol            | Parameter                                  | Rating  | Unit       |      |
|-------------------|--|---------|------------|------|
| Common Rat        | ings (Tc=25C Unless Otherwise Noted)       |         |            |      |
| VDSS              | Drain-Source Voltage                       |         | 100        | V    |
| Vgss              | Gate-Source Voltage                        |         | ±20        | V    |
| TJ                | Junction Temperature Range                 |         | 55 1, 475  | С    |
| Тѕтс              | Storage Temperature Range                  |         | -55 to 175 | C    |
| Is                | Source Current-Continuous(Body Diode)      | Tc=25℃  | 135        | Α    |
| Mounted on        | Large Heat Sink                            |         | •          |      |
| Ірм               | Pulsed Drain Current *                     | Tc=25℃  | 400        | А    |
| 1                 | Continuous Davis Comment                   | Tc=25°C | 135        | Α    |
| lσ                | Continuous Drain Current                   | Tc=100℃ | 95.4       | Α    |
| Б                 | Maria de Branco Biolina di a               | Tc=25℃  | 208.3      | W    |
| P <sub>D</sub>    | Maximum Power Dissipation Tc=100C          |         | 104.2      | W    |
| R <sub>0</sub> JC | Thermal Resistance, Junction-to-Case       | 0.72    | °C/W       |      |
| $R_{\theta JA}$   | Thermal Resistance, Junction-to-Ambient ** |         | 62.5       | °C/W |
| Eas               | Single Pulsed-Avalanche Energy ***         | L=0.3mH | 490        | mJ   |

Note: \* Repetitive rating; pulse width limited by max.junction temperature.

### Electrical Characteristics(Tc =25°C Unless Otherwise Noted)

| Compleal            | Danamatan                         | Took Condit   | Test Conditions |     | HYG053N10NS3 |      | l lm!t |
|---------------------|-----------------------------------|---|-----------------|-----|--------------|------|--------|
| Symbol              | Parameter                         | lest Condit   |                 |     | Тур.         | Max  | Unit   |
| Static Cha          | Static Characteristics            |   |                 |     |              |      |        |
| BVDSS               | Drain-Source Breakdown Voltage    | V <sub>GS</sub> =0V,I <sub>DS</sub> =250μ/                | Ą               | 100 | -            | -    | V      |
| 1                   | Due in the Course Lookens Current | V <sub>DS</sub> =100V,V <sub>GS</sub> =0\                 | /               | -   | -            | 1    | μA     |
| IDSS                | Drain-to-Source Leakage Current   | T   | J=125℃          | -   | -            | 50   | μA     |
| V <sub>GS(th)</sub> | Gate Threshold Voltage            | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250µA |                 | 2.2 | 3            | 3.8  | V      |
| lgss                | Gate-Source Leakage Current       | $V_{GS}=\pm 20V, V_{DS}=0V$                               |                 | -   | -            | ±100 | nA     |
| RDS(ON)             | Drain-Source On-State Resistance  | V <sub>GS</sub> =10V,I <sub>DS</sub> =50A                 |                 | -   | 5            | 5.6  | mΩ     |
| Diode Cha           | Diode Characteristics             |   |                 |     |              |      |        |
| VsD                 | Diode Forward Voltage             | IsD=50A,VGS=0V  |                 | -   | 0.92         | 1.1  | V      |
| trr                 | Reverse Recovery Time             | 50A H / H 400A/w  |                 | -   | 64           | -    | ns     |
| Qrr                 | Reverse Recovery Charge           | IsD=50A,dIsD/dt=100A/µs                                   |                 | -   | 120          | -    | nC     |

<sup>\*\*</sup> Surface mounted on 1in2 FR-4 board.

<sup>\*\*\*</sup> Limited by TJmax , starting TJ=25°C , L = 0.3mH, Rg= 25 $\Omega$ , Vgs =10V.

# HYG053N10NS3P&B



# Electrical Characteristics (Cont.) (Tc =25°C Unless Otherwise Noted)

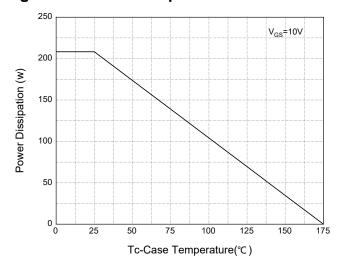
| Compleal             | Boromotor                               | Took Conditions                                   | HY  | HYG053N10NS3 |     |      |  |
|----------------------|---|---|-----|--------------|-----|------|--|
| Symbol               | Parameter                               | Test Conditions                                   | Min | Тур.         | Max | Unit |  |
| Dynamic (            | Dynamic Characteristics                 |   |     |              |     |      |  |
| Rg                   | Gate Resistance                         | V <sub>GS</sub> =0V,V <sub>DS</sub> =0V, f=300kHz | -   | 2.1          | -   | Ω    |  |
| Ciss                 | Input Capacitance                       | V <sub>G</sub> s=0V,                              | -   | 4123         | -   |      |  |
| Coss                 | Output Capacitance                      | V <sub>DS</sub> =50V,                             | -   | 592          | -   | pF   |  |
| Crss                 | Reverse Transfer Capacitance            | f=300kHz  | -   | 15           | -   |      |  |
| td(ON)               | Turn-on Delay Time                      |   | -   | 17           | -   |      |  |
| Tr                   | Turn-on Rise Time                       | $V_{DD}$ =50 $V$ , $R_{G}$ =2.5 $\Omega$ ,        | -   | 75           | -   |      |  |
| td(OFF)              | Turn-off Delay Time                     | Ips=50A,Vgs=10V                                   | -   | 32           | -   | ns   |  |
| Tf                   | Turn-off Fall Time                      |   | -   | 45           | -   |      |  |
| Gate Char            | ge Characteristics                      |   |     |              | •   |      |  |
| Qg                   | Total Gate Charge(V <sub>GS</sub> =10V) |   | -   | 58           | -   |      |  |
| Qgs                  | Gate-Source Charge                      | \/ -90\/   -50A                                   | -   | 25           | -   | nC   |  |
| Qgd                  | Gate-Drain Charge                       | $V_{DS}$ =80V, $I_{DS}$ =50A                      | -   | 12           | -   |      |  |
| V <sub>plateau</sub> | Gate plateau voltage                    |   | -   | 6            | -   | V    |  |

Note: \*Pulse test, pulse width  $\leq 300$ us, duty cycle  $\leq 2\%$ 



## **Typical Operating Characteristics**

**Figure 1: Power Dissipation** 



**Figure 2: Drain Current** 

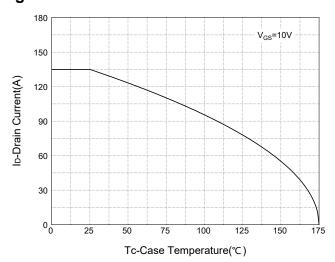


Figure 3: Safe Operation Area

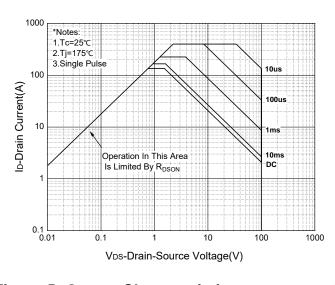


Figure 4: Thermal Transient Impedance

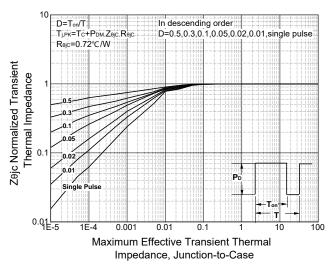


Figure 5: Output Characteristics

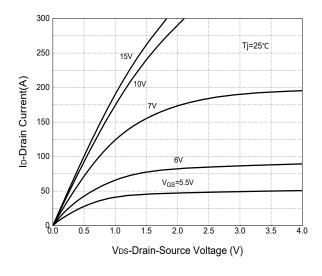
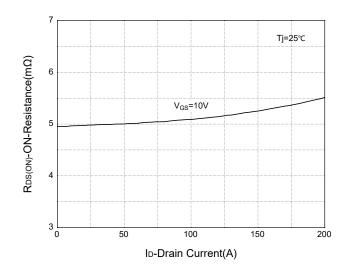


Figure 6: Drain-Source On Resistance





### **Typical Operating Characteristics(Cont.)**

Figure 7: On-Resistance vs. Temperature

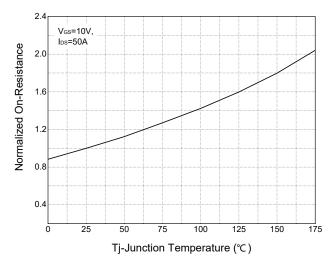


Figure 8: Source-Drain Diode Forward

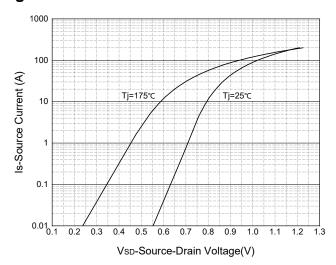
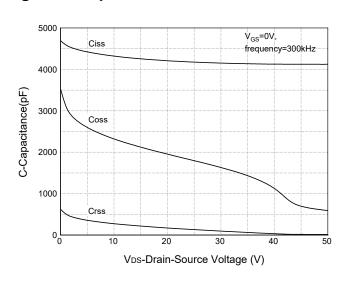
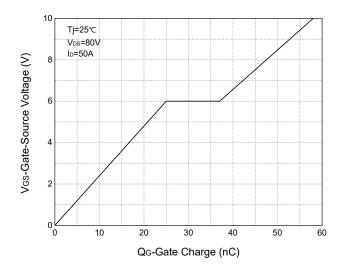


Figure 9: Capacitance Characteristics

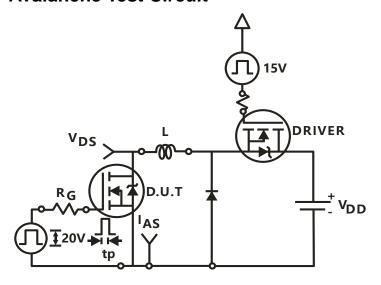


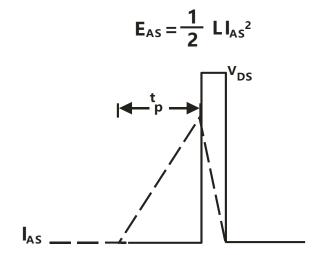
**Figure 10: Gate Charge Characteristics** 



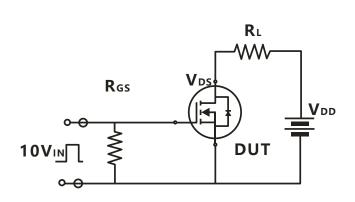


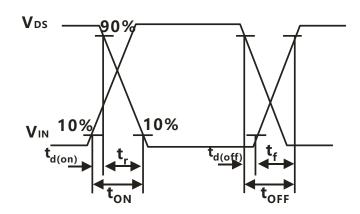
### **Avalanche Test Circuit**



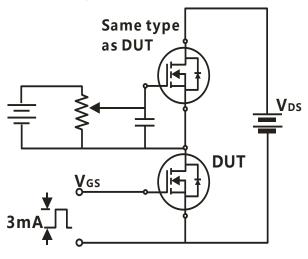


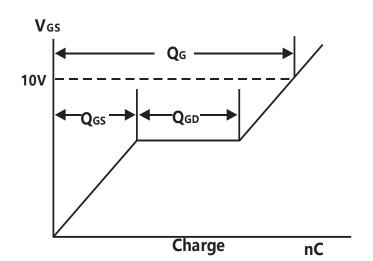
## **Switching Time Test Circuit**





## **Gate Charge Test Circuit**







MAX

4.70

1.40

2.60

0.95

1.47

0.60

16.10

9.40

7.10

10.30

8.60

6.85

13.80

3.40 3.80

3.00

BSC

BSC

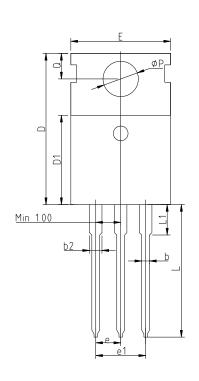
### **Device Per Unit**

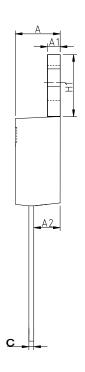
| Package Type | Unit | Quantity |
|--------------|------|----------|
| TO-220FB-3L  | Tube | 50       |
| TO-263-2L    | Reel | 800      |

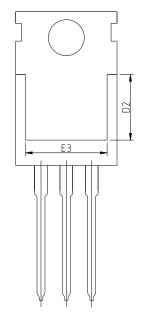
## **Package Information**

TO-220FB-3L

С







| SYMBOL MIN NOW          |                     |                    |                                |                |  |  |
|-------------------------|---------------------|--------------------|--------------------------------|----------------|--|--|
| COMMON DIMENSIANS 4.37  |                     |                    |                                |                |  |  |
| SYMBOL                  |                     | mmA1               | 1.25                           | 1.30           |  |  |
| STIVIBUL                | MIN                 | $NOM^2$            | MAX                            | 2. 40          |  |  |
| Α                       | 4.37                | 4.57 <sub>h2</sub> | 0. 70<br><b>1</b> . <b>7</b> 7 | 1. 27          |  |  |
| A1                      | 1.25                | 1.30 <sub>C</sub>  | 140                            | 0.50           |  |  |
| A2                      | 2.20                | 2.40 <sup>D</sup>  | 125.600                        | 15. 60         |  |  |
| b                       | 0.70                | $0.80^{01}_{02}$   | 0.95<br>5.95                   | 9. 10<br>6. 30 |  |  |
| b2                      | 1.17                | 1.27 <sub>E</sub>  | 9. <b>4</b> 7                  | 10.00          |  |  |
| С                       | 0.45                | <b>0.50</b> E3     | 0.60                           | 7.80           |  |  |
| D                       | 15.10               | 15.60 <sup>e</sup> | 16.10                          | 2. 54<br>5. 08 |  |  |
| D1                      | 8.80                | 9.10 <sup>e1</sup> | <b>9.49</b>                    | 6. 50          |  |  |
| D2                      | 5.50                | 6.30⊥              | 172.1703                       | 13.50          |  |  |
| Е                       | 9.70                | 10.001             | 10.30                          | 3. 10          |  |  |
| E3                      | 7.00                | 7.80 <sup>P</sup>  | 8.60<br>8.60                   | 3. 60 2. 80    |  |  |
| е                       | 2.54 BSC            |                    | ]                              |                |  |  |
| e1                      | FA 37               |                    |                                |                |  |  |
| NOM N<br>H1<br>4 57 4   | <sup>fAX</sup> 6.25 | 6.50               | 6.85                           |                |  |  |
| 1. 90 1.                | 40 <b>12.75</b>     | 13.50              | 13.80                          |                |  |  |
| 2. <b><u>14</u>0</b> 2. |                     | 3.10               | 3.40                           |                |  |  |
| 0.80 0                  | 95                  |                    |                                | 7              |  |  |

3.60

2.80

3.80

3.00

| A1      | 1.25           | 1. <del>§</del> 0     | 1.40           | 12.75 |
|---------|----------------|-----------------------|----------------|-------|
| A2      | 2.20           | 2. <b>L40</b>         | 2.60           | _     |
| b       | 0.70           | <b>₽</b>              | 0.95           | 3.40  |
| b2<br>c | 1. 17<br>0. 45 | 1. 27<br>0 <b>Q</b> 0 | 1. 47<br>0. 60 | 2.60  |
| D       | 15. 10         | 15.60                 | 16. 10         |       |
| D1      | 8.80           | 9.10                  | 9.40           |       |
| D2      | 5.50           | 6.30                  | 7.10           |       |
| Е       | 9.70           | 10.00                 | 10.30          |       |
| E3      | 7.00           | 7.80                  | 8.60           |       |
| е       |                | 2.54                  | BSC            |       |
| e1      |                | 5.08                  | BSC            |       |
| H1      | 6.25           | 6.50                  | 6.85           |       |
| L       | 12.75          | 13.50                 | 13.80          |       |

3.10 3.40

3.60

2.80

3.80

3.00

SYMBOL MIN A

4.37

3.40

2.60

L1

ΦР

Q

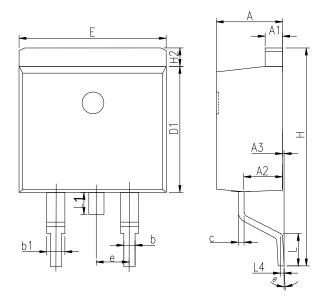


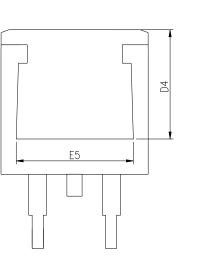
 $\mathsf{MAX}$ 4.77 1.42 2.89 0.25 0.96 1.47 0.53 8.90

10.36

15.50 1.47 2.60 1.70

#### TO-263-2L



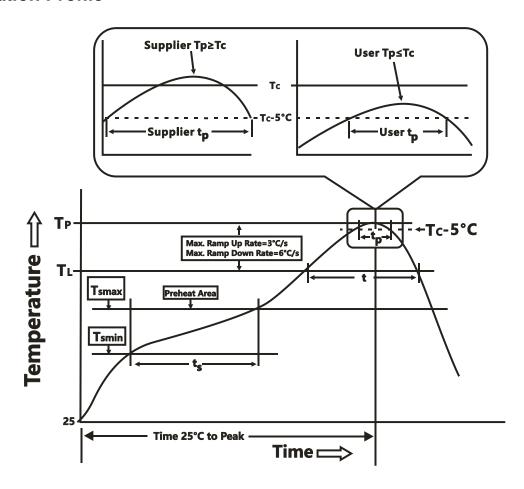


| SYMBOL  |
|---------|
| OTWIDOL |
| Α       |
| A1      |
| A2      |
| A3      |
| b       |
| b1      |
| С       |
| D1      |
| D4      |
| Е       |
| E5      |
| е       |
| Н       |
| H2      |
| L       |
| L1      |
| L4      |
| θ       |
| . •     |

| b 0.70 0.8<br>b1 1.17 1.2<br>c 0.30 0.3                       |       | 1.47<br>0.53  |
|---|-------|---------------|
| COMMON DIMENSIONS D1 8.50 8.7                                 | -     | 8.90<br>-     |
| SYMBOL   mm E 9.86   10.                                      | 16 1  | 10.36         |
| MIN NOM e MIN 2   |       | SC            |
| A 4.37 4.57 H 14.70 15.                                       |       | 15.50<br>1.47 |
| A1 122 127 L <sub>1.4</sub> 2.00 2.3                          | 30 2  | 2.60<br>1.70  |
| A2 2.49 2.69 L4 2.89 0  | .25 B |               |
| A3 0 0.13 0.25 5  |       | 9-            |
| b 0.70 0.81 0.96  |       |               |
| b1 1.17 1.27 1.47   |       |               |
| MIN dNOM MAX 0.30 0.38 0.53                                   |       |               |
| 4.37 4.57 4.77<br>1.22 D <sub>1</sub> (27 1.42 8.50 8.70 8.90 |       |               |
| 2.49 D <sub>2</sub> 469 2.89 6.60                             |       |               |
| 0.70 £0.81 0.96 9.86 10.16 10.36                              |       |               |
| 0.30 <b>E5</b> 38   |       |               |
| 8.50 8.70 8.90<br>6.60 e _                                    |       |               |
| 9.86 H <sup>0.16</sup> 10.3614.70 15.10 15.50                 |       |               |
| H2 <sup>2.54</sup> BSC 1.07 1.27 1.47                         |       |               |
| 1.07 L1.27 1.47 2.00 2.30 2.60                                |       |               |
| 2.00 2.30 2.60<br>1.40 L1.55 1.70 1.40 1.55 1.70              |       |               |
| L4 <sup>0.25</sup> BSC 0.25 BSC                               |       |               |
| θ 0° 5° 9°  |       |               |



### **Classification Profile**



### **Classification Reflow Profiles**

| Profile Feature                                      | Sn-Pb Eutectic Assembly            | Pb-Free Assembly                 |
|--|------------------------------------|----------------------------------|
|  | Preheat & Soak                     |                                  |
| Temperature min (T <sub>smin</sub> )                 | 100 °C                             | 150 °C                           |
| Temperature max (T <sub>smax</sub> )                 | 150 °C                             | 200 °C                           |
| Time (Tsmin to Tsmax) (t <sub>s</sub> )              | 60-120 seconds                     | 60-120 seconds                   |
| Average ramp-up rate                                 | 3 °C/second max.                   | 3°C/second max.                  |
| (T <sub>smax</sub> to T <sub>P</sub> )               | 3 C/second max.                    | 5 C/second max.                  |
| Liquidous temperature (T <sub>L</sub> )              | 183 °C                             | 217 °C                           |
| Time at liquidous (t∟)                               | 60-150 seconds                     | 60-150 seconds                   |
| Peak package body Temperature                        | See Classification Temp in table 1 | SacClassification Tampin table 2 |
| (T <sub>p</sub> )*                                   | See Classification Temp in table 1 | SeeClassification Tempin table 2 |
| Time (t <sub>P</sub> )** within 5°C of the specified | 20** seconds                       | 20** 000000                      |
| classification temperature (T <sub>c</sub> )         | 20 seconds                         | 30** seconds                     |
| Average ramp-down rate (Tpto Tsmax)                  | 6 °C/second max.                   | 6 °C/second max.                 |
| Time 25°C to peak temperature                        | 6 minutes max.                     | 8 minutes max.                   |

<sup>\*</sup>Tolerance for peak profile Temperature (Tp) is defined as a supplier minimum and a user maximum.

<sup>\*\*</sup> Tolerance for time at peak profile temperature (t<sub>p</sub>) is defined as a supplier minimum and a user maximum.

## HYG053N10NS3P&B



Table 1.SnPb Eutectic Process – Classification Temperatures (Tc)

| Package<br>Thickness | Volume mm³<br><350 | Volume mm³<br>≥350 |
|----------------------|--------------------|--------------------|
| <2.5 mm              | 235 °C             | 220 °C             |
| ≥2.5 mm              | 220 °C             | 220 °C             |

Table 2.Pb-free Process – Classification Temperatures (Tc)

| Package         | Volume mm <sup>3</sup> | Volume mm³ | Volume mm³ |
|-----------------|------------------------|------------|------------|
| Thickness       | <350                   | 350-2000   | ≥2000      |
| <1.6 mm         | 260 °C                 | 260 °C     | 260 °C     |
| 1.6 mm – 2.5 mm | 260 °C                 | 250 °C     | 245 °C     |
| ≥2.5 mm         | 250 °C                 | 245 °C     | 245 °C     |

## **Reliability Test Program**

| Test item     | Method        | Description                                |
|---------------|---------------|--|
| SOLDERABILITY | JESD-22, B102 | 5 Sec, 245°C                               |
| HTRB          | JESD-22, A108 | 168/500 Hrs, Bias @ 150℃                   |
| HTGB          | JESD-22, A108 | 168 /500 Hrs, V <sub>gs</sub> 100% @ 150°C |
| PCT           | JESD-22, A102 | 96 Hrs, 100%RH, 2atm, 121°C                |
| тст           | JESD-22, A104 | 500/1000Cycles, -55°C~150°C                |

#### **Customer Service**

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